

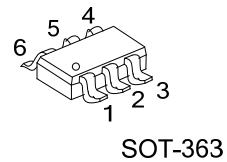
2N7002DW

Power MOSFET

**300mA, 60V DUAL
N-CHANNEL POWER MOSFET**

■ DESCRIPTION

The UTC **2N7002DW** uses advanced technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with low gate voltages. This device is suitable for use as a load switch or in PWM applications.

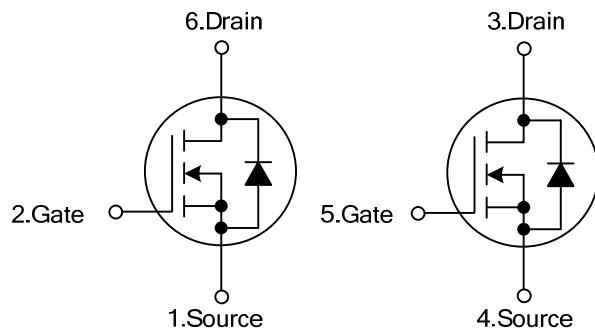


SOT-363

■ FEATURES

- * High Density Cell Design for Low $R_{DS(ON)}$.
- * Voltage Controlled Small Signal Switch
- * Rugged and Reliable
- * High Saturation Current Capability

■ SYMBOL

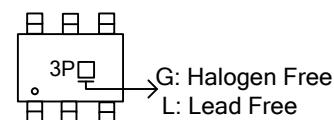


■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment						Packing
Lead Free	Halogen Free		1	2	3	4	5	6	
2N7002DWL-AL6-R	2N7002DWG-AL6-R	SOT-363	S1	G1	D2	S2	G2	D1	Tape Reel

2N7002DWG-AL6-R	(1)Packing Type (2)Package Type (3)Halogen Free	(1) R: Tape Reel (2) AL6: SOT-363 (3) G: Halogen Free, L: Lead Free
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■ MARKING



■ ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$, unless otherwise noted.)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	60	V
Drain-Gate Voltage ($R_{GS} \leq 1\text{M}\Omega$)		V_{DGR}	60	V
Gate Source Voltage	Continuous	V_{GSS}	± 20	V
	Non Repetitive($t_p < 50\mu\text{s}$)		± 40	
Drain Current	Continuous	I_D	300	mA
	Pulsed		800	
Power Dissipation		P_D	200	mW
Derated Above 25°C			1.6	$\text{mW}/^\circ\text{C}$
Junction Temperature		T_J	+ 150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55 ~ +150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient		θ_{JA}	625 (Note1)	$^\circ\text{C}/\text{W}$

■ ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0\text{V}, I_D=10\mu\text{A}$	60			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=60\text{V}, V_{GS}=0\text{V}$			1	μA
Gate-Source Leakage Current	I_{GSSF}	$V_{GS}=20\text{V}, V_{DS}=0\text{V}$			100	nA
	I_{GSSR}	$V_{GS}=-20\text{V}, V_{DS}=0\text{V}$			-100	nA
ON CHARACTERISTICS (Note 2)						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS}=V_{DS}, I_D=250\mu\text{A}$	1	2.1	2.5	V
Drain-Source On-Voltage	V_{DS} (ON)	$V_{GS}=10\text{V}, I_D=300\text{mA}$		0.6	3.75	V
		$V_{GS}=5.0\text{V}, I_D=50\text{mA}$		0.09	1.5	
Static Drain-Source On-Resistance	R_{DS} (ON)	$V_{GS}=10\text{V}, I_D=300\text{mA}, T_J=125^\circ\text{C}$			13.5	Ω
		$V_{GS}=5.0\text{V}, I_D=50\text{mA}$			7.5	Ω
DYNAMIC CHARACTERISTICS						
Input Capacitance	C_{ISS}	$V_{DS}=25\text{V}, V_{GS}=0\text{V}, f=1.0\text{MHz}$		20	50	pF
Output Capacitance	C_{OSS}			11	25	pF
Reverse Transfer Capacitance	C_{RSS}		4	5		pF
Turn-On Time	t_{ON}	$V_{DD}=30\text{V}, R_L=150\Omega$ $I_D=200\text{mA}, V_{GS}=10\text{V}$ $R_{GEN}=25\Omega$			20	nS
Turn-Off Time	t_{OFF}	$V_{DD}=30\text{V}, R_L=25\Omega$ $I_D=200\text{mA}, V_{GS}=10\text{V}$ $R_{GEN}=25\Omega$			20	nS
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0\text{V}, I_S=300\text{mA}$ (Note)		0.88	1.5	V
Maximum Pulsed Drain-Source Diode Forward Current	I_{SM}				0.8	A
Maximum Continuous Drain-Source Diode Forward Current	I_S				300	mA

Note: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch. Minimum land pad size.

2. Pulse Test: Pulse Width≤300μs, Duty Cycle≤2.0%

■ TEST CIRCUIT AND WAVEFORM

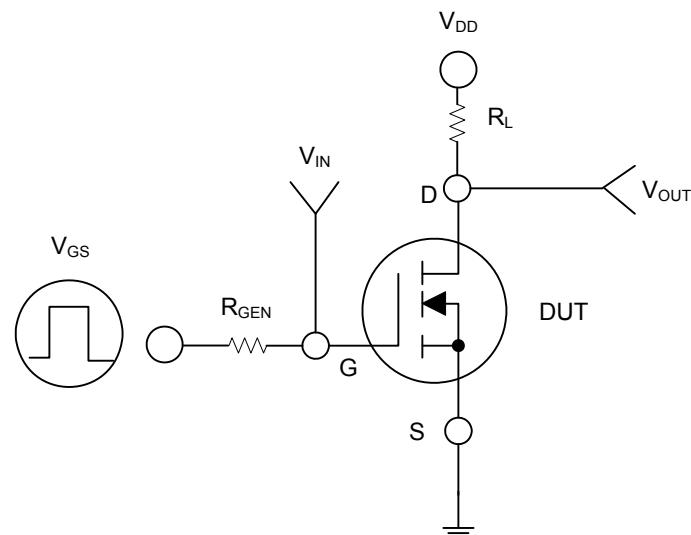


Fig. 1

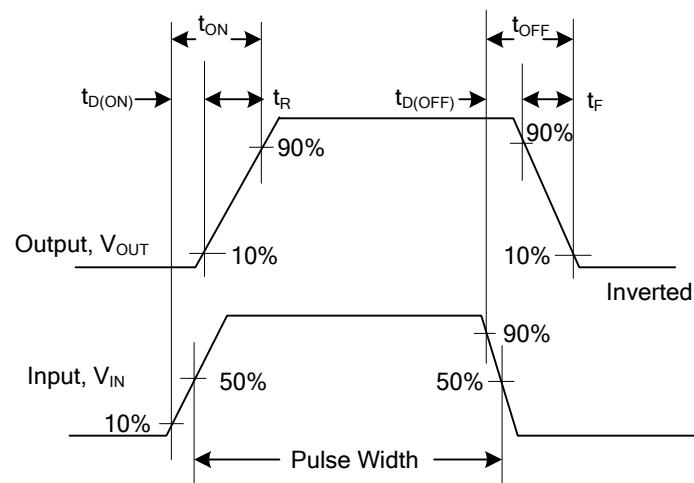
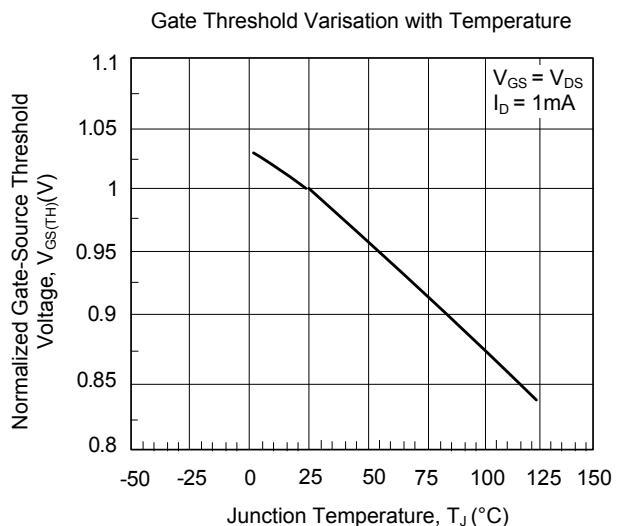
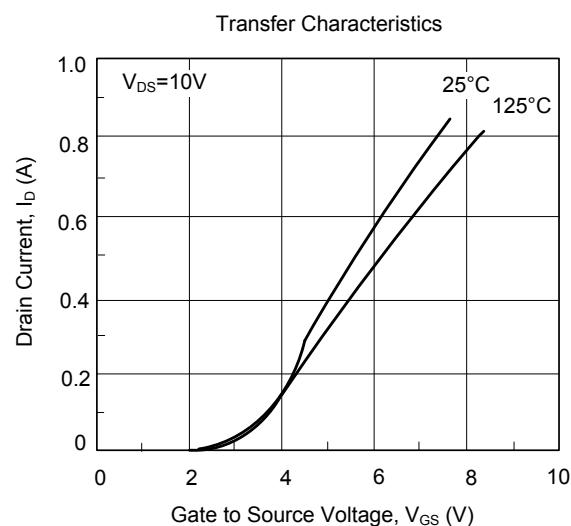
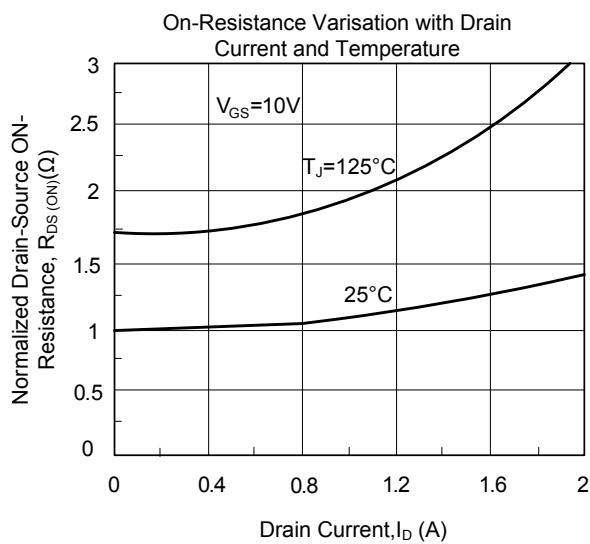
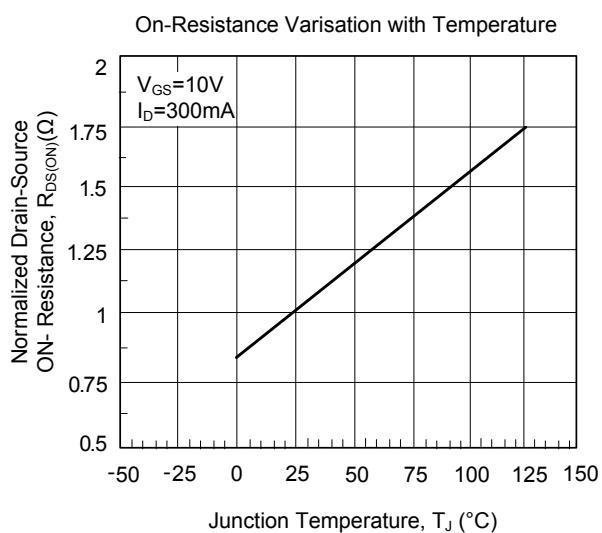
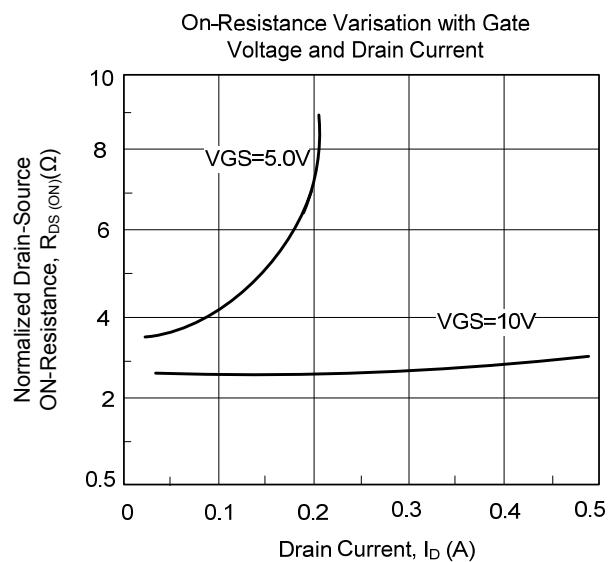
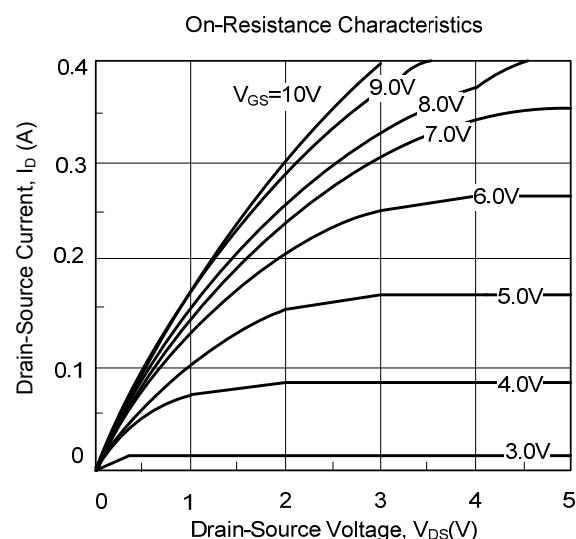
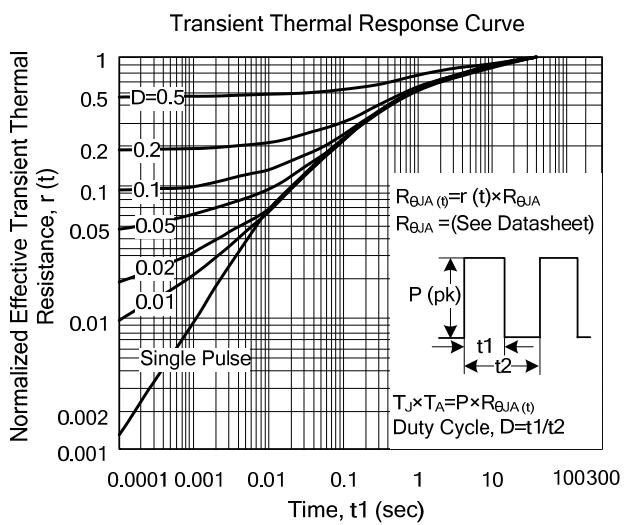
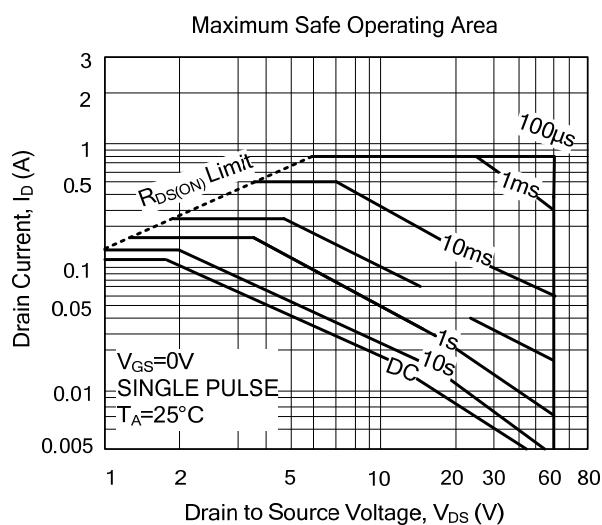
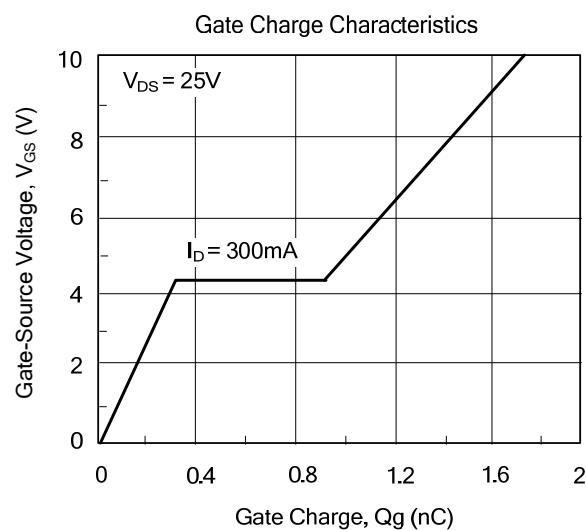
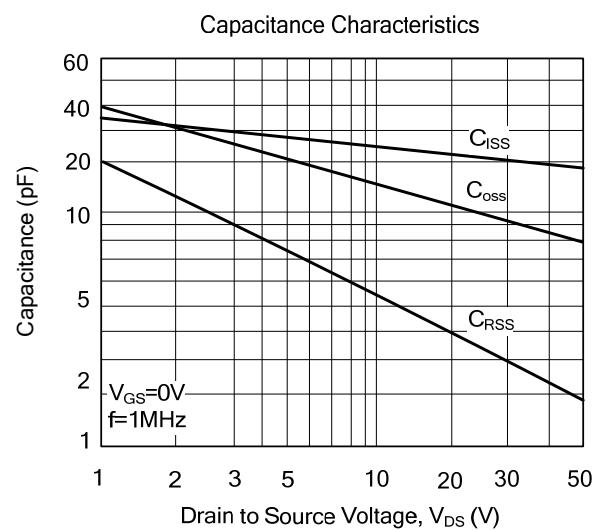
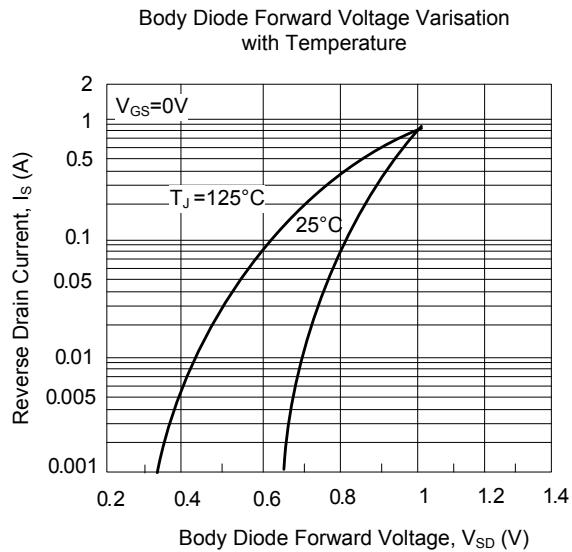
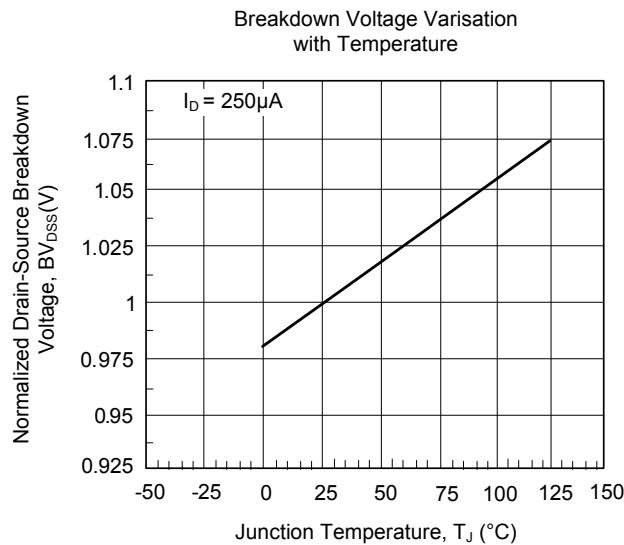


Fig. 2 Switching Waveforms

■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



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